

Over voltage and over current protection IC

Descriptions

The WS3202E is an Over-Voltage-Protection (OVP) and Over-Current-Protection (OCP) device. The device will switch off internal MOSFET to disconnect IN to OUT to protect load when any of input voltage, input current over the threshold. The Over temperature protection (OTP) function monitors chip temperature to protect the device.

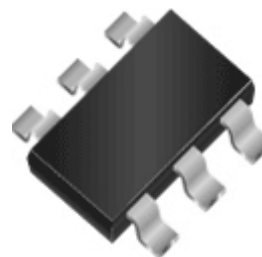
The WS3202E is available in SOT-23-6L package. Standard products are Pb-free and Halogen-free.

Features

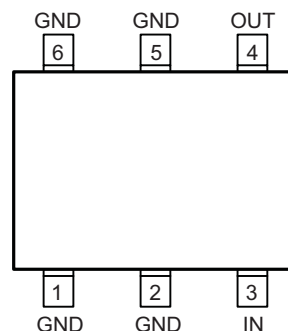
- High voltage technology
- Maximum input voltage : 25V
- Output power ON time : 8ms (Typ.)
- OVP threshold : 6.1V (Typ.)
- OVP response time : <1us
- OCP threshold : 2A (Min.)
- Output discharge
- Package : SOT-23-6L

Applications

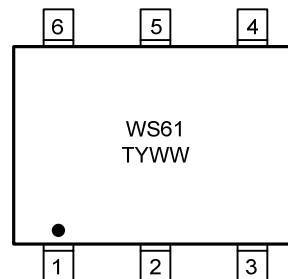
- GPS
- PMP
- MID
- PAD
- Digital cameras
- Digital Videos



SOT-23-6L



Pin configuration (Top view)



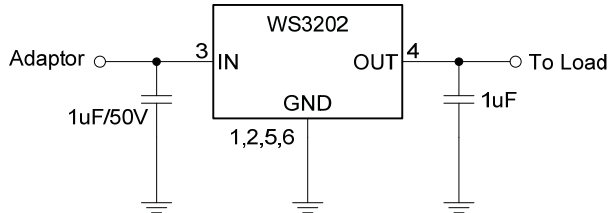
WS61 = Device code
T = Series code
Y = Year
WW = Week

Marking

Order information

Device	Package	Shipping
WS3202E61-6/TR	SOT-23-6L	3000/Reel&Tape

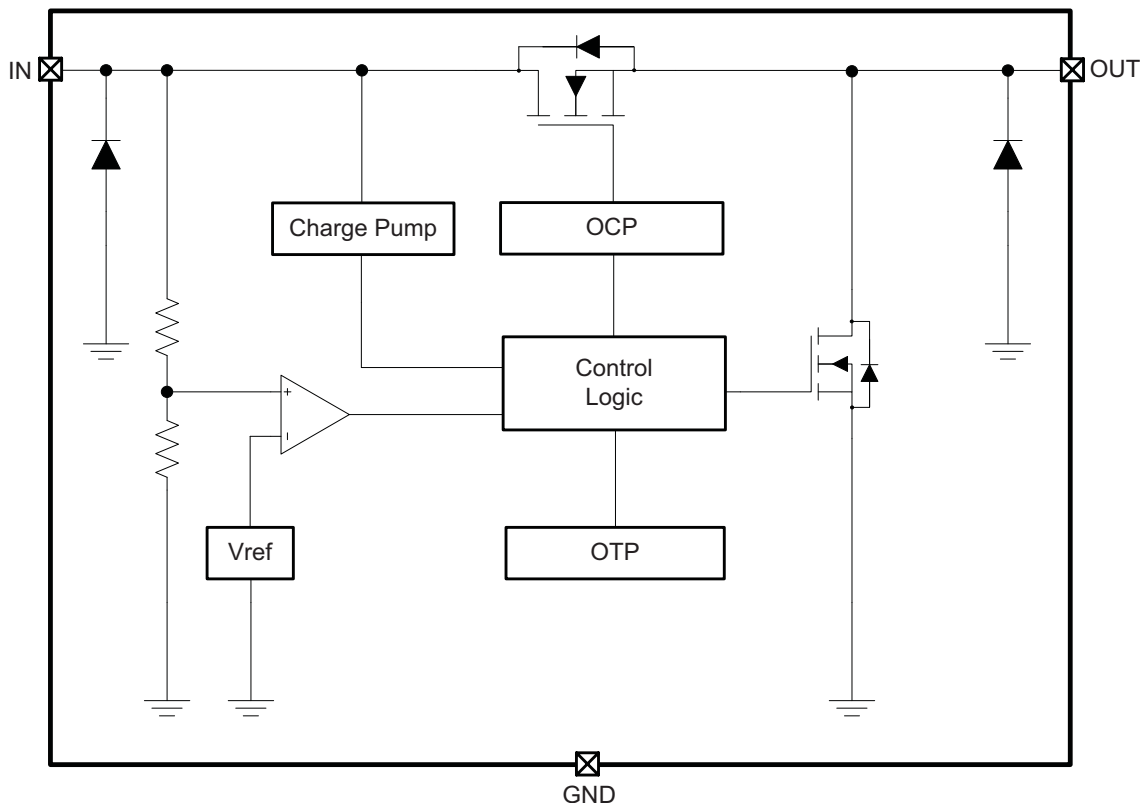
Typical applications



Pin descriptions

Pin No.	Symbol	Descriptions
1, 2, 5, 6	GND	Power ground
3	IN	Input pin, connect to AC adaptor or VBUS. A 1uF low ESR ceramic capacitor or larger must be connected as close as to this pin. It is recommended to use 50V capacitor or according to application.
4	OUT	Output pin, Connect to load.

Block diagram



Absolute maximum ratings

Parameter	Symbol	Value	Unit
Input voltage (IN pin)	V_{IN}	-0.3 ~ 25	V
Output voltage (OUT pin)	V_{OUT}	-0.3 ~ 6.5	V
Power dissipation *1 *3	P_D	0.5	W
Power dissipation *2 *3		0.3	W
Thermal resistance *1	$R_{\theta JA}$	250	°C/W
Thermal resistance *2		416	°C/W
Junction temperature	T_J	150	°C
Lead temperature(10s)	T_L	260	°C
Storage temperature	Tstg	-55 ~ 150	°C
ESD Ratings	HBM	±8000	V
	MM	±1000	V

Note: These are stress ratings only. Stresses exceeding the range specified under “Absolute Maximum Ratings” may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

*1: Surface mounted on FR-4 Board using 1 square inch pad size, dual side, 1oz copper

*2: Surface mounted on FR-4 board using minimum pad size, 1oz copper

*3: Power dissipation is calculated by $P_D = (V_{IN} - V_{OUT}) \times I_{OUT}$

Recommend operating conditions (Ta=25°C, unless otherwise noted)

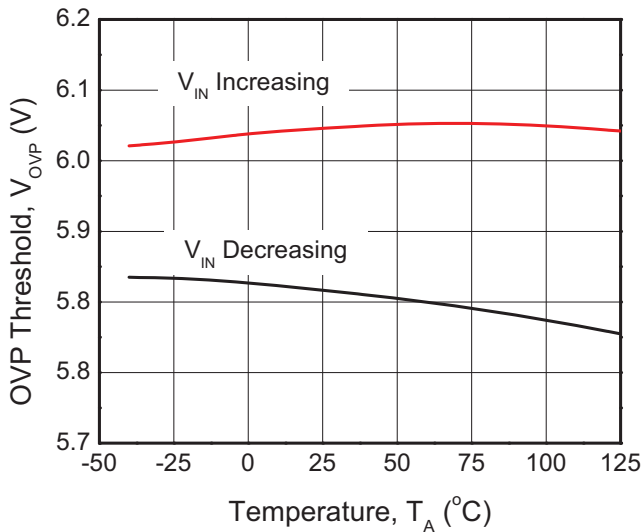
Parameter	Symbol	Value	Unit
Input voltage	V_{IN}	3 ~ 24	V
Output current	I_{OUT}	1.5	A
Ambient operating temperature	Topr	-40 ~ 85	°C

Electronics Characteristics (Ta=25°C, unless otherwise noted)

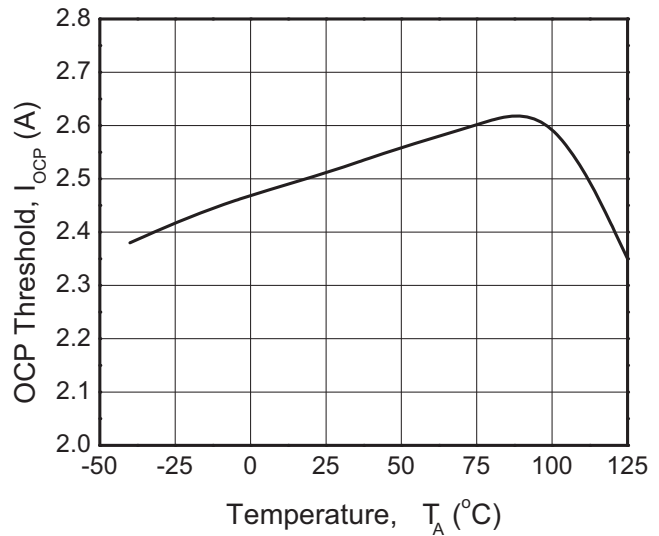
Parameter	Symbol	Test conditions	Min.	Typ.	Max.	Unit
DC characteristics and Power-ON-Reset						
Input quiescent current	I _Q	V _{IN} =5V, I _{OUT} =0A		280	350	uA
IN-to-OUT ON resistance *3	R _{ON}	V _{IN} =5V, I _{OUT} =0.7A		190	220	mΩ
Output discharge resistance	R _{DISCHARGE}			500		Ω
Under voltage lock out threshold	UVLO	V _{IN} increasing from 0~3V	2.3		2.8	V
Under voltage lock out hysteresis	V _{HYS-UVLO}	V _{IN} decreasing from 3~0V	200	250	300	mV
Output power-on time	T _{ON}	V _{IN} = 0 -> 5V to output ON	6	8	10	ms
Input Over-Voltage-Protection (OVP)						
OVP threshold	V _{OVP}	V _{IN} increasing from 5~7V	5.8	6.1	6.4	V
OVP hysteresis	V _{HYS-OVP}	V _{IN} decreasing from 7~5V	200	300	400	mV
OVP active time	T _{OVP}	V _{IN} = 5 -> 10V			1	us
OVP recovery time	T _{ON(OVP)}	V _{IN} = 10 -> 5V to output ON	6	8	10	ms
Input Over-Current-Protection (OCP)						
OCP threshold	I _{OCP}		2.0	2.5	3.3	A
OCP active time	T _{OCP}			176		us
OCP recovery time	T _{ON(OCP)}			1		s
Over-Temperature-Protection (OTP)						
OTP threshold				165		°C
OTP hysteresis				40		°C

*3: Single Pulse, Pulse width=10ms

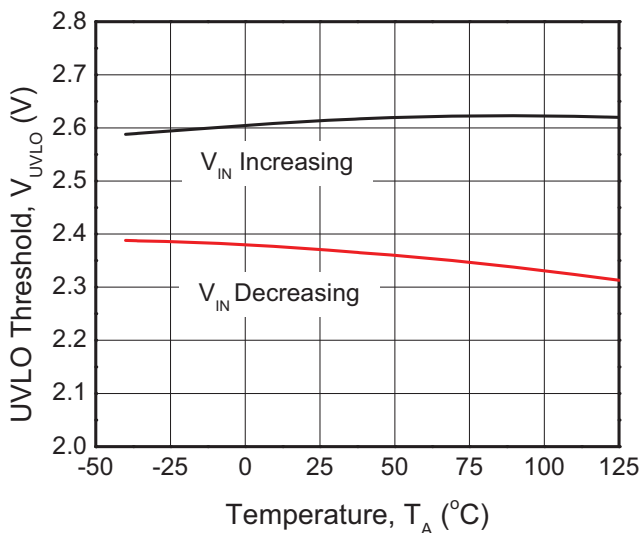
Typical Characteristics (Ta=25°C, unless otherwise noted)



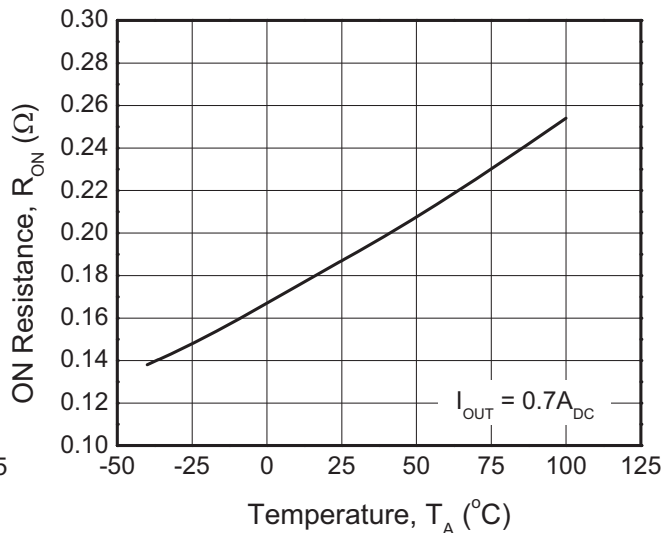
OVP threshold vs. Temperature



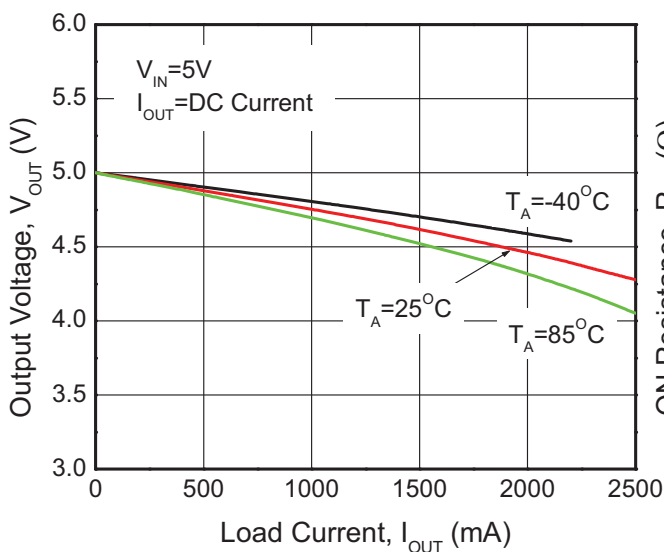
OCP threshold vs. Temperature



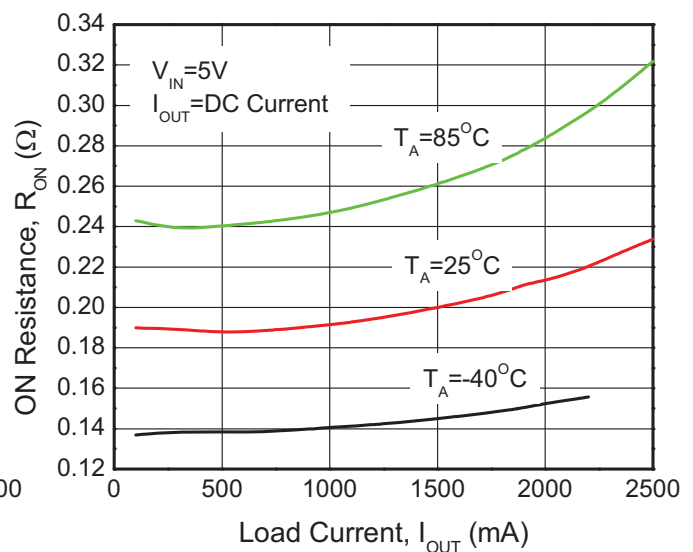
UVLO threshold vs. Temperature



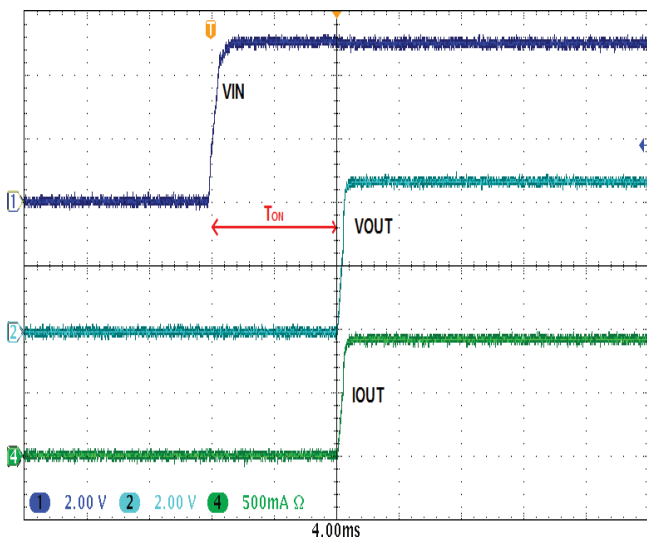
IN-to-OUT ON resistance vs. Temperature



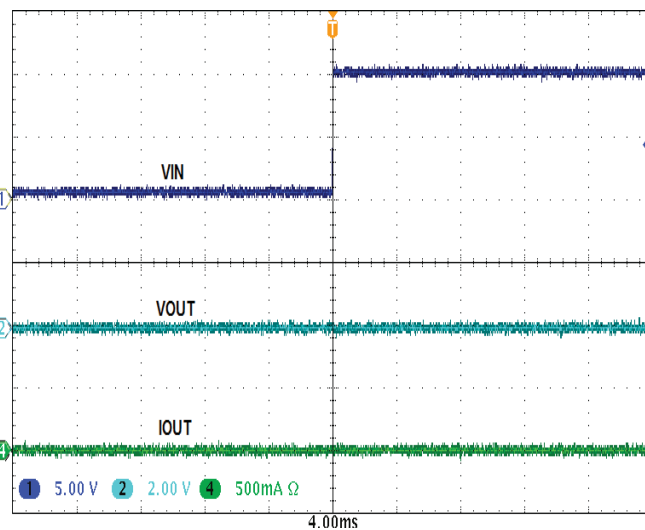
Output voltage vs. Output current



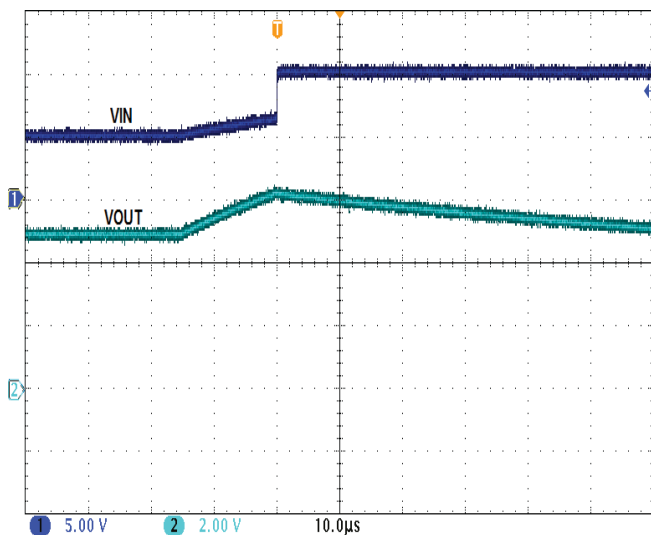
ON resistance vs. Output current



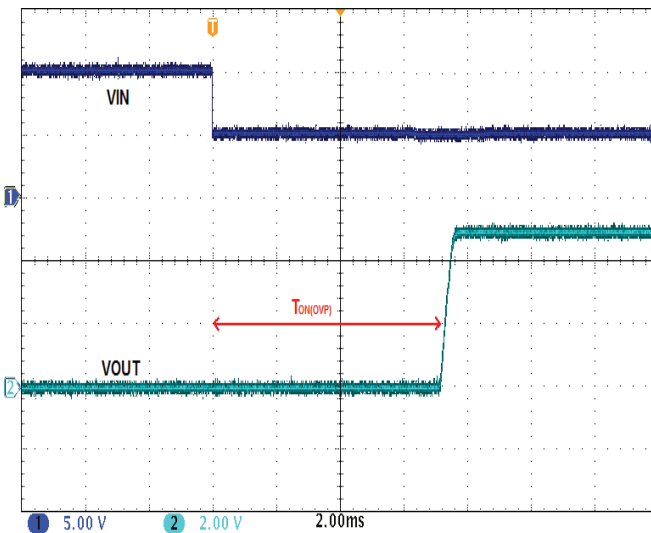
Normally Power ON



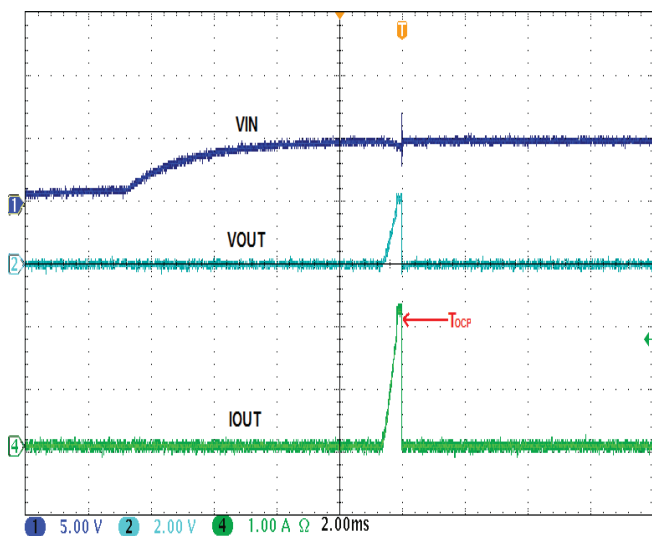
Power ON with Input Overvoltage



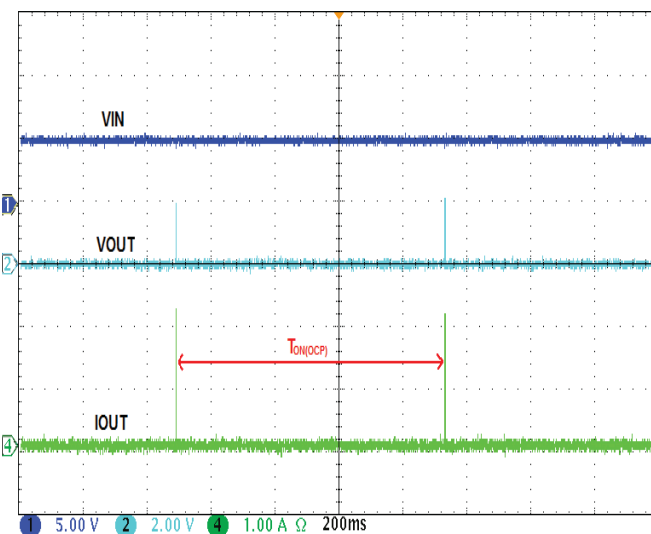
OVP Active Time



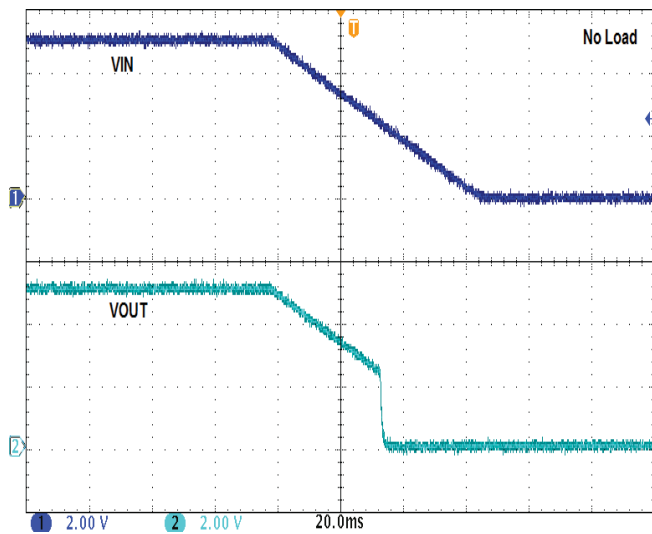
OVP Recovery Time



OCP Active Time



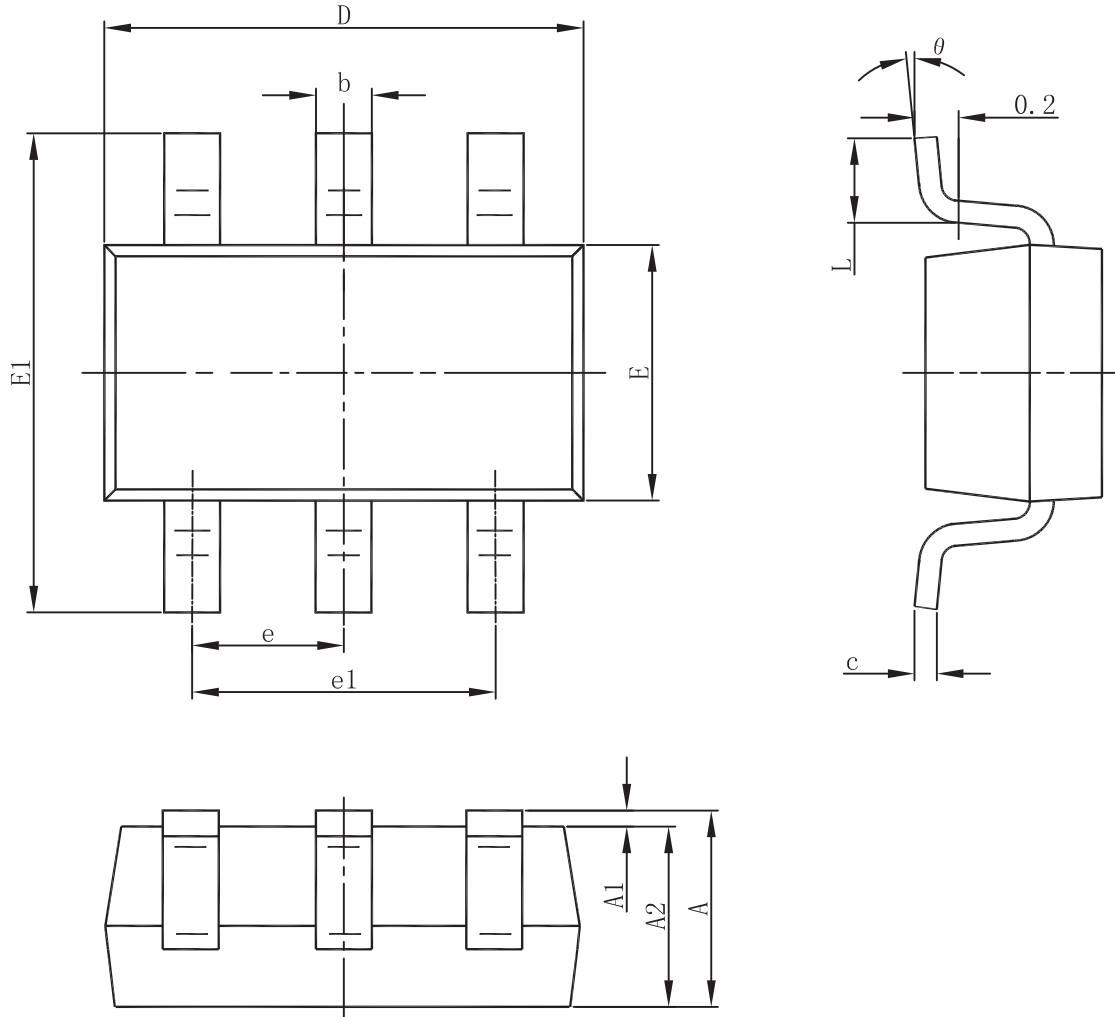
OCP Recovery Time



Normally Power OFF

Package outline dimensions

SOT-23-6L



Symbol	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	1.050	-	1.250
A1	0.000	-	0.100
A2	1.050	-	1.150
b	0.300	0.400	0.500
c	0.100	-	0.200
D	2.820	2.900	3.020
E	1.500	1.600	1.700
E1	2.650	2.800	2.950
e	0.950 Typ.		
e1	1.800	1.900	2.000
L	0.300	-	0.600
θ	0°	-	8°